HALOGEN

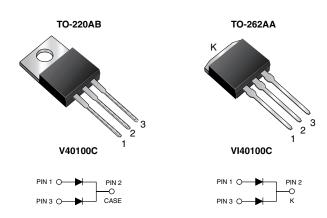
FREE



Vishay General Semiconductor

Dual High Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.38 \text{ V}$ at $I_F = 5 \text{ A}$



| PRIMARY CHARACTERISTICS | | | | | | |
|-------------------------|--------------------|--|--|--|--|--|
| I _{F(AV)} | 2 x 20 A | | | | | |
| V_{RRM} | 100 V | | | | | |
| I _{FSM} | 250 A | | | | | |
| V_F at $I_F = 20 A$ | 0.61 V | | | | | |
| T _J max. | 150 °C | | | | | |
| Package | TO-220AB, TO-262AA | | | | | |
| Circuit configurations | Common cathode | | | | | |

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | |
|----------------------------------------------------------------------------------------------|------------------|--------------------|---------|----------|------|
| PARAMETER | | SYMBOL | V40100C | VI40100C | UNIT |
| Max. repetitive peak reverse voltage | | V_{RRM} | 100 | | V |
| Max. average forward rectified current (fig. 1) | per device | 1 | 40 | | А |
| | per diode | I _{F(AV)} | 20 | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | I _{FSM} | 250 | | А | |
| Voltage rate of change (rated V _R) | | dV/dt | 10 | 000 | V/µs |
| Operating junction temperature range | | TJ | -40 to | +150 | °C |
| Storage temperature range | | T _{stg} | -55 to | +150 | °C |



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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | | |
|-----------------------------------------------------------------------------------|-----------------------|-------------------------|-------------------------------|------|------|------|--|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | | |
| Instantaneous forward voltage per diode | I _F = 5 A | T _A = 25 °C | V _F ⁽¹⁾ | 0.47 | - | V | | |
| | I _F = 10 A | | | 0.54 | - | | | |
| | I _F = 20 A | | | 0.67 | 0.73 | | | |
| | I _F = 5 A | T _A = 125 °C | | 0.38 | - | | | |
| | I _F = 10 A | | | 0.45 | - | | | |
| | I _F = 20 A | | 0.61 | 0.67 | | | | |
| Reverse current at rated V _R per diode | V _R = 70 V | T _A = 25 °C | I _R (2) | 9 | - | μΑ | | |
| | | T _A = 125 °C | | 10 | 1 | mA | | |
| | | T _A = 25 °C | | - | 1000 | μΑ | | |
| | | T _A = 125 °C | | 21 | 45 | mA | | |

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | |
|-------------------------------------------------------------------------|----------------|------------------|--|------|--|
| PARAMETER | SYMBOL | V40100C VI40100C | | UNIT | |
| Typical thermal resistance per diode | $R_{	heta JC}$ | 2.0 | | °C/W | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-220AB | V40100C-M3/4W | 1.85 | 4W | 50/tube | Tube | | |
| TO-262AA | VI40100C-M3/4W | 1.45 | 4W | 50/tube | Tube | | |

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

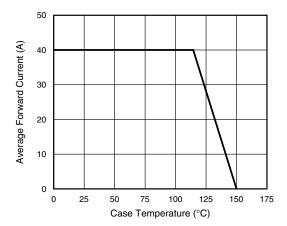


Fig. 1 - Forward Current Derating Curve

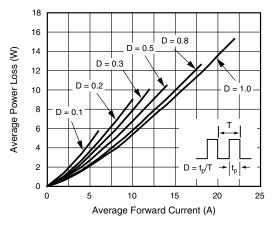


Fig. 2 - Forward Power Loss Characteristics Per Diode

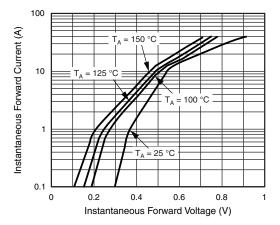


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

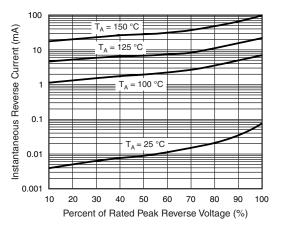


Fig. 4 - Typical Reverse Characteristics Per Diode

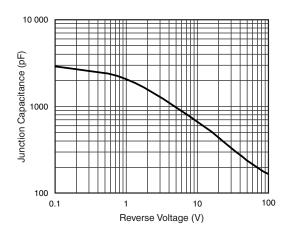


Fig. 5 - Typical Junction Capacitance Per Diode

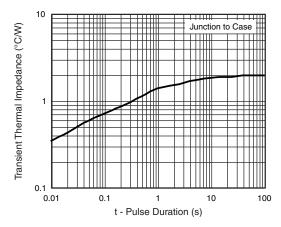
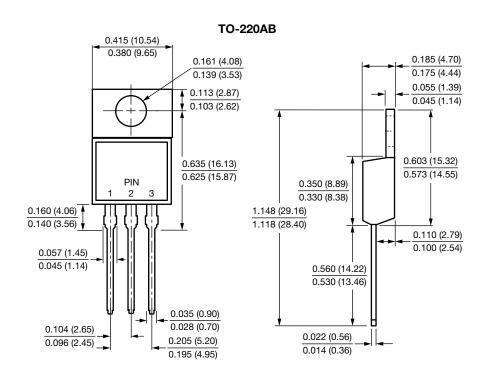


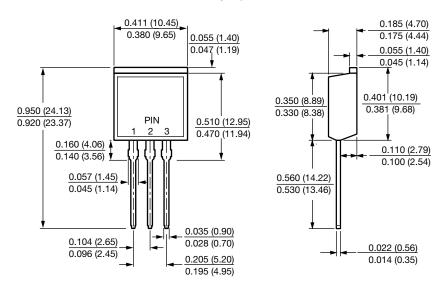
Fig. 6 - Typical Transient Thermal Impedance Per Diode

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-262AA





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